BLS9G2731L-400; BLS9G2731LS-400 LDMOS S-band radar power transistor

AMMPLEON

Rev. 1 — 13 April 2017

Product data sheet

Product profile

1.1 General description

400 W LDMOS power transistor for S-band applications in the frequency range from 2700 MHz to 3100 MHz.

Test information Table 1.

Typical RF performance at T_{case} = 25 °C; t_{p} = 300 μs ; δ = 10 %; I_{Dq} = 400 mA; in a class-AB demo circuit measured over the entire 2700 MHz to 3100 MHz frequency range.

| Test signal | f | V _{DS} | P_L | G _p | η_{D} |
|-------------|--------------|-----------------|-------|----------------|------------|
| | (MHz) | (V) | (W) | (dB) | (%) |
| pulsed RF | 2700 to 3100 | 32 | 425 | 13 | 47 |

1.2 Features and benefits

- High efficiency
- Excellent ruggedness
- Designed for S-band radar applications
- Excellent thermal stability
- Easy power control
- Integrated dual sided ESD protection enables excellent off-state isolation
- High flexibility with respect to pulse formats
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

S-band radar applications in the frequency range from 2700 MHz to 3100 MHz

2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline | Graphic symbol |
|------------|-----------------|--------------------|--------------------|
| BLS9G2731L | 400 (SOT502A) | | |
| 1 | drain | | |
| 2 | gate | 5 1 3 | 1 |
| 3 | source [1] | 2 | 2 3 3 sym112 |
| BLS9G2731L | S-400 (SOT502B) | | 5,2 |
| 1 | drain | 1 | 1 |
| 2 | gate | 3 | l "Li |
| 3 | source [1] | 2 | 2 3 3 sym112 |

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

| Type number | Packag | ackage | | | |
|-----------------|--------|--|---------|--|--|
| | Name | Description | Version | | |
| BLS9G2731L-400 | - | flanged ceramic package; 2 mounting holes; 2 leads | SOT502A | | |
| BLS9G2731LS-400 | - | earless flanged ceramic package; 2 leads | SOT502B | | |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|----------------------|------------|-----|------|------|
| V_{DS} | drain-source voltage | | - | 65 | V |
| V_{GS} | gate-source voltage | | -6 | +13 | V |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | [1] | - | 225 | °C |

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Тур | Unit |
|----------------------|--|---|------|------|
| Z _{th(j-c)} | transient thermal impedance from junction to | T _{case} = 85 °C; P _L = 400 W | | |
| | case | t_p = 100 μ s; δ = 10 % | 0.11 | K/W |
| | | t_p = 300 μ s; δ = 10 % | 0.15 | K/W |
| | | t_p = 500 μ s; δ = 10 % | 0.17 | K/W |
| | | t_p = 1000 μ s; δ = 10 % | 0.18 | K/W |

6. Characteristics

Table 6. DC characteristics

 T_i = 25 °C unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|----------------------------------|--|-----|------|-----|------|
| V _{(BR)DSS} | drain-source breakdown voltage | $V_{GS} = 0 \text{ V}; I_D = 4.5 \text{ mA}$ | 65 | - | - | V |
| V _{GS(th)} | gate-source threshold voltage | V _{DS} = 10 V; I _D = 450 mA | 1.5 | 1.9 | 2.5 | V |
| I _{DSS} | drain leakage current | V _{GS} = 0 V; V _{DS} = 32 V | - | - | 4 | μΑ |
| I _{DSX} | drain cut-off current | $V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$ | - | 85 | - | Α |
| I _{GSS} | gate leakage current | V _{GS} = 11 V; V _{DS} = 0 V | - | - | 400 | nA |
| g _{fs} | forward transconductance | V _{DS} = 10 V; I _D = 450 mA | - | 4.2 | - | S |
| R _{DS(on)} | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 15.75 \text{ A}$ | - | 0.03 | - | Ω |

Table 7. RF characteristics

Test signal: pulsed RF; t_p = 300 μ s; δ = 10 %; RF performance at V_{DS} = 32 V; I_{Dq} = 400 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production circuit measured at frequencies of 2700 MHz, 2900 MHz and 3100 MHz.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------------|---------------------------------------|------------------------|-----|-----|-----|------|
| Gp | power gain | P _L = 425 W | 11 | 13 | - | dB |
| RLin | input return loss | P _L = 425 W | - | -7 | - | dB |
| η_{D} | drain efficiency | P _L = 425 W | 44 | 47 | - | % |
| P _{droop(pulse)} | pulse droop power | P _L = 425 W | - | 0.0 | 0.3 | dB |
| t _r | rise time | P _L = 425 W | - | 6 | 50 | ns |
| t _f | fall time | P _L = 425 W | - | 6 | 50 | ns |
| P _{L(3dB)} | output power at 3 dB gain compression | | 400 | - | - | W |

7. Test information

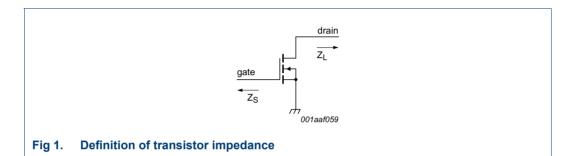
7.1 Ruggedness in class-AB operation

The BLS9G2731L-400 and BLS9G2731LS-400 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dq} = 100 mA; P_{L} = 400 W; t_{p} = 300 μ s; δ = 10 %.

7.2 Impedance information

Table 8. Typical impedance

| f | Z _S | Z_L |
|-------|----------------|------------|
| (MHz) | (Ω) | (Ω) |
| 2700 | 1.6 – j5.8 | 1.6 – j3.7 |
| 2800 | 2.9 – j6.6 | 1.8 – j3.6 |
| 2900 | 8.0 – j4.7 | 2.2 – j3.1 |
| 3000 | 4.4 – j0.3 | 1.9 – j2.4 |
| 3100 | 1.9 – j0.7 | 1.5 – j2.1 |



7.3 Test circuit

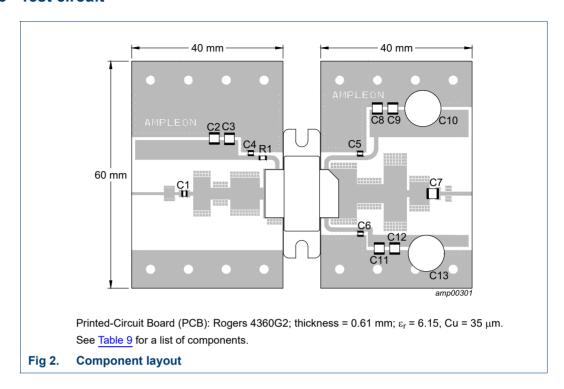
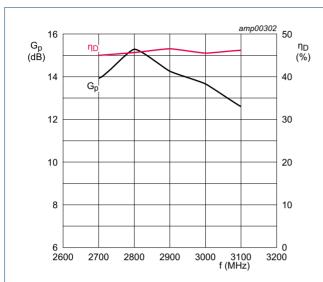


Table 9.List of componentsSee Figure 2 for component layout.

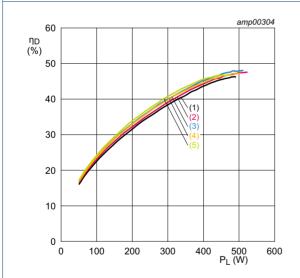
| Component | Description | Value | Remarks |
|-------------|-----------------------------------|--------------|----------------------------|
| C1 | multilayer ceramic chip capacitor | 12 pF | ATC 800A |
| C2, C8, C11 | multilayer ceramic chip capacitor | 1 nF | ATC 800B |
| C3, C9, C12 | multilayer ceramic chip capacitor | 10 μF | Murata: GRM55DR61H106KA88L |
| C4, C5, C6 | multilayer ceramic chip capacitor | 15 pF | ATC 800A |
| C7 | multilayer ceramic chip capacitor | 33 pF | ATC 800B |
| C10, C13 | electrolytic capacitor | 100 μF, 63 V | |
| R1 | resistor | 5 Ω | SMD 0603 |

7.4 Graphical data



 V_{DS} = 32 V; I_{Dq} = 400 mA; P_L = 425 W; t_p = 300 $\mu s;$ δ = 10 %.

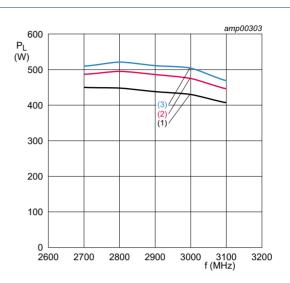




 V_{DS} = 32 V; I_{Dq} = 400 mA; t_p = 300 μ s; δ = 10 %.

- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2900 MHz
- (4) f = 3000 MHz
- (5) f = 3100 MHz

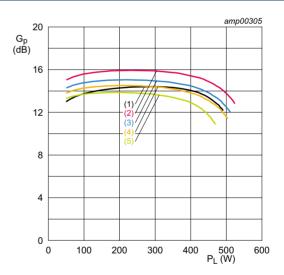
Fig 5. Drain efficiency as a function of output power; typical values



 V_{DS} = 32 V; I_{Dq} = 400 mA; t_p = 300 $\mu s;$ δ = 10 %.

- (1) P_{1dB}
- (2) P_{2dB}
- (3) P_{3dB}

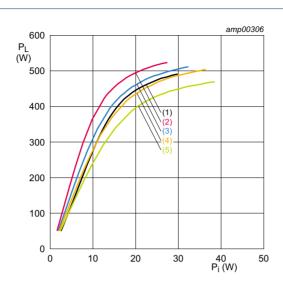
Fig 4. Output power as a function of frequency; typical values



 V_{DS} = 32 V; I_{Dq} = 400 mA; t_p = 300 μ s; δ = 10 %.

- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2900 MHz
- (4) f = 3000 MHz
- (5) f = 3100 MHz

Fig 6. Power gain as a function of output power; typical values

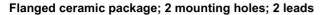


 V_{DS} = 32 V; I_{Dq} = 400 mA; t_p = 300 μ s; δ = 10 %.

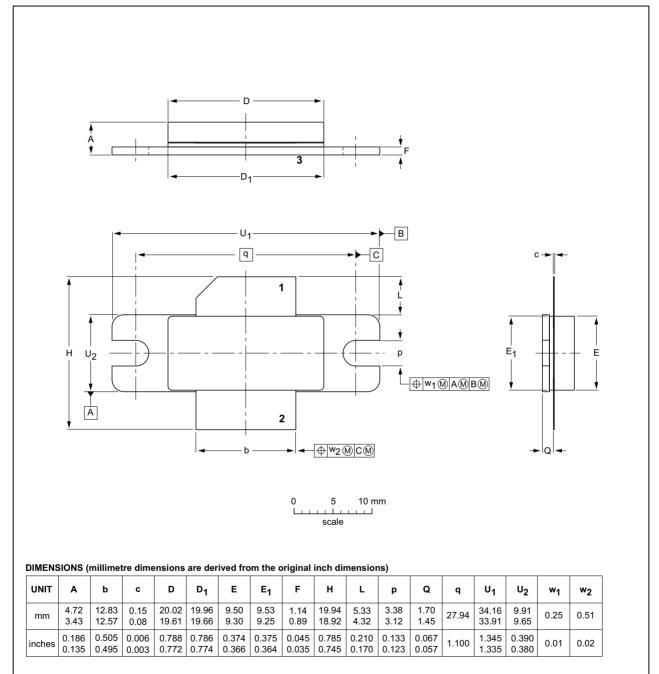
- (1) f = 2700 MHz
- (2) f = 2800 MHz
- (3) f = 2900 MHz
- (4) f = 3000 MHz
- (5) f = 3100 MHz

Fig 7. Output power as a function of input power; typical values

8. Package outline



SOT502A



| OUTLINE | | REFERENCES | | | EUROPEAN | ISSUE DATE |
|---------|-----|------------|-------|--|------------|------------------------------------|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE |
| SOT502A | | | | | | -03-01-10 - 12-05-02 |

Fig 8. Package outline SOT502A

Earless flanged ceramic package; 2 leads

SOT502B

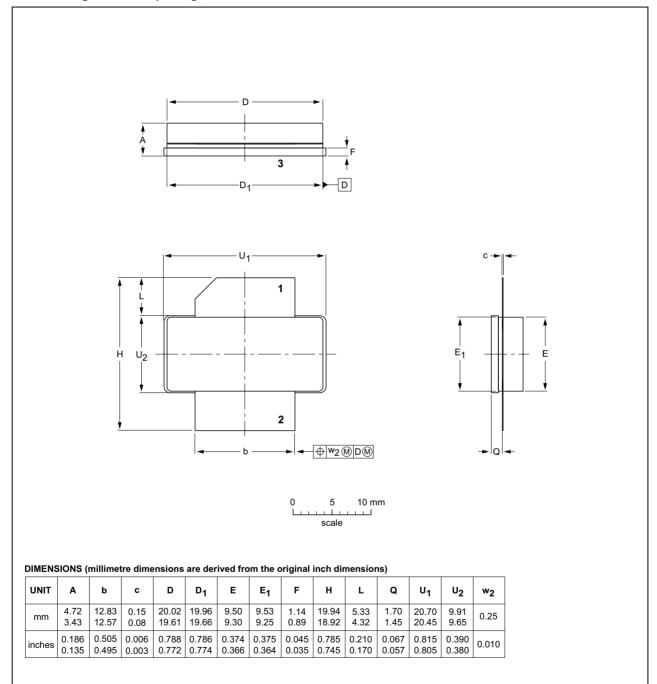


Fig 9. Package outline SOT502B

IEC

OUTLINE

VERSION

SOT502B

JEITA

REFERENCES

JEDEC

ISSUE DATE

07-05-09

12-05-02

EUROPEAN

PROJECTION

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 10. ESD sensitivity

| ESD model | Class |
|--|---------|
| Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002 | C2A [1] |
| Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001 | 2 [2] |

- [1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V, but fails after exposure to an ESD pulse of 750 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

10. Abbreviations

Table 11. Abbreviations

| Acronym | Description |
|---------|--|
| ESD | ElectroStatic Discharge |
| LDMOS | Laterally Diffused Metal-Oxide Semiconductor |
| MTF | Median Time to Failure |
| S-band | Short wave band |
| SMD | Surface Mounted Device |
| VSWR | Voltage Standing-Wave Ratio |

11. Revision history

Table 12. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|---------------------------|--------------|--------------------|---------------|------------|
| BLS9G2731L-400_LS-400 v.1 | 20170413 | Product data sheet | | - |

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|--------------------------------|-------------------|---|
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LDMOS S-band radar power transistor

14. Contents

| 1 | Product profile |
|------|----------------------------------|
| 1.1 | General description |
| 1.2 | Features and benefits |
| 1.3 | Applications |
| 2 | Pinning information |
| 3 | Ordering information |
| 4 | Limiting values |
| 5 | Thermal characteristics |
| 6 | Characteristics |
| 7 | Test information |
| 7.1 | Ruggedness in class-AB operation |
| 7.2 | Impedance information |
| 7.3 | Test circuit |
| 7.4 | Graphical data 6 |
| 8 | Package outline |
| 9 | Handling information |
| 10 | Abbreviations |
| 11 | Revision history |
| 12 | Legal information 11 |
| 12.1 | Data sheet status 1 |
| 12.2 | Definitions |
| 12.3 | Disclaimers 1 |
| 12.4 | Trademarks12 |
| 13 | Contact information |
| 14 | Contents 13 |

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